

Features

- Trench LV MOSFET Technology
- ESD Protected up to 2KV(HBM)
- Moisture Sensitivity Level 1
- Halogen Free. "Green" Device (Note 1)
- Epoxy Meets UL 94 V-0 Flammability Rating
- Lead Free Finish/RoHS Compliant ("P" Suffix Designates RoHS Compliant. See Ordering Information)

Maximum Ratings

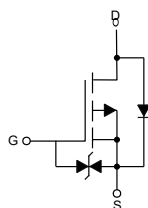
- Operating Junction Temperature Range: -55°C to +150°C
- Storage Temperature Range: -55°C to +150°C
- Thermal Resistance: 160°C/W Junction to Ambient (Note 2)

Parameter		Symbol	Rating	Unit
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±8	V
Drain Current-Continuous	$T_A=25^\circ\text{C}$	I_D	-0.95	A
	$T_A=100^\circ\text{C}$		-0.60	
Pulsed Drain Current (Note 3)		I_{DM}	-3.8	A
Power Dissipation (Note 4)		P_D	0.78	W

Note:

1. Halogen free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
2. The value of $R_{\theta JA}$ is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with $T_A=25^\circ\text{C}$.
3. Repetitive rating; pulse width limited by max. junction temperature.
4. P_D is based on max. junction temperature, using junction-ambient thermal resistance.

Internal Structure and Marking Code

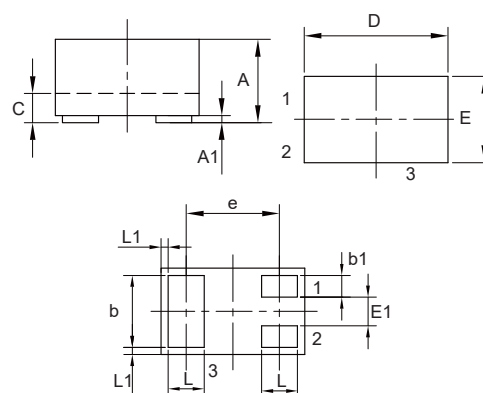


1. GATE
2. SOURCE
3. DRAIN



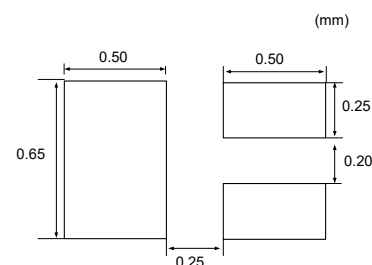
P-Channel MOSFET

DFN1006-3



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.017	0.022	0.42	0.55	
A1	0.000	0.002	0.00	0.05	
b	0.018	0.022	0.45	0.55	
b1	0.004	0.008	0.10	0.20	
c	0.005	0.007	0.12	0.18	
D	0.037	0.041	0.95	1.05	
E	0.022	0.026	0.55	0.65	
E1	0.006	0.010	0.15	0.25	
e	0.026		0.65		TYP.
L	0.008	0.012	0.20	0.30	
L1	0.0002		0.05		TYP.

Suggested Solder Pad Layout



Electrical Characteristics @ 25°C (Unless Otherwise Specified)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} =0V, I _D =-250μA	-20			V
Gate-Source Leakage Current	I _{GSS}	V _{DS} =0V, V _{GS} =±8V			± 10	μA
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = -20V, V _{GS} =0V			-1	μA
Gate-Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250μA	-0.35	-0.62	-1.2	V
Drain-Source On-Resistance	R _{DS(on)}	V _{GS} =-4.5V, I _D =-0.5A		428	580	mΩ
		V _{GS} =-2.5V, I _D =-0.5A		545	720	
		V _{GS} =-1.8V, I _D =-0.1A		653	1050	
		V _{GS} =-1.5V, I _D =-0.05A		790	1350	
		V _{GS} =-1.2V, I _D =-0.01A		1130	2100	
Gate Resistance	R _g	f=1 MHz, Open drain		3614		Ω
Diode Characteristics						
Continuous Body Diode Current	I _S				-0.95	A
Diode Forward Voltage	V _{SD}	V _{GS} =0V, I _S =-0.3A			-1.2	V
Reverse Recovery Time	t _{rr}	I _F =-0.5A, dI _F /dt=33A/μs		324		ns
Reverse Recovery Charge	Q _{rr}			115		nC
Dynamic Characteristics						
Input Capacitance	C _{iss}	V _{DS} = -10V,V _{GS} =0V,f=1MHz		27		pF
Output Capacitance	C _{oss}			9.5		
Reverse Transfer Capacitance	C _{rss}			3		
Total Gate Charge	Q _g	V _{DD} = -10V,V _{GS} =-4.5V,I _D = -0.5A		1.2		nC
Gate-Source Charge	Q _{gs}			0.29		
Gate-Drain Charge	Q _{gd}			0.32		
Turn-On Delay Time	t _{d(on)}	V _{DD} =-10V, V _{GS} =-4.5V , R _G =3Ω, I _D =-0.5A		3.2		ns
Turn-On Rise Time	t _r			4.7		
Turn-Off Delay Time	t _{d(off)}			754		
Turn-Off Fall Time	t _f			713		

Curve Characteristics

Fig.1 - Typical Output Characteristics

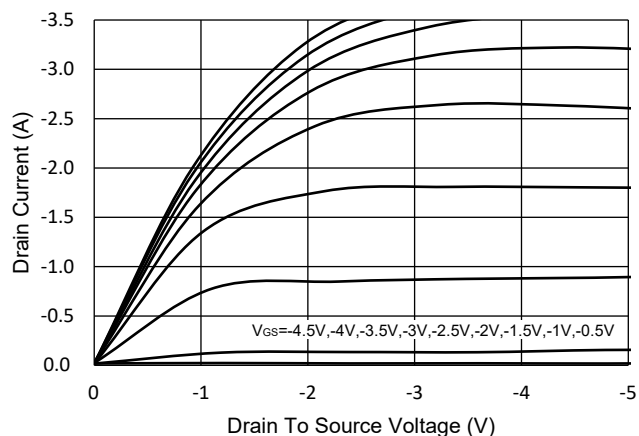


Fig.2 - Transfer Characteristic

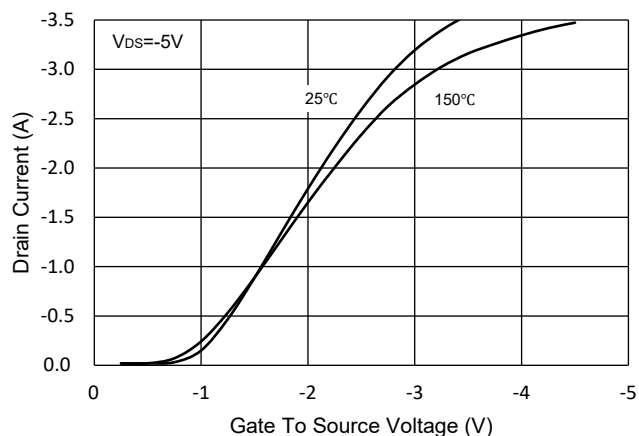


Fig.3 - $R_{DS(ON)}$ - V_{GS}

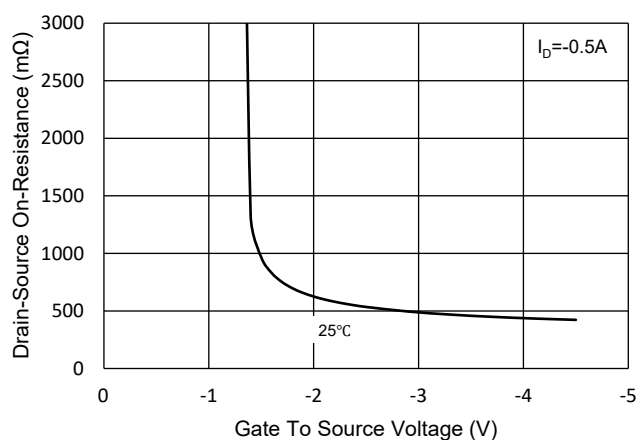


Fig.4 - $R_{DS(ON)}$ - I_D

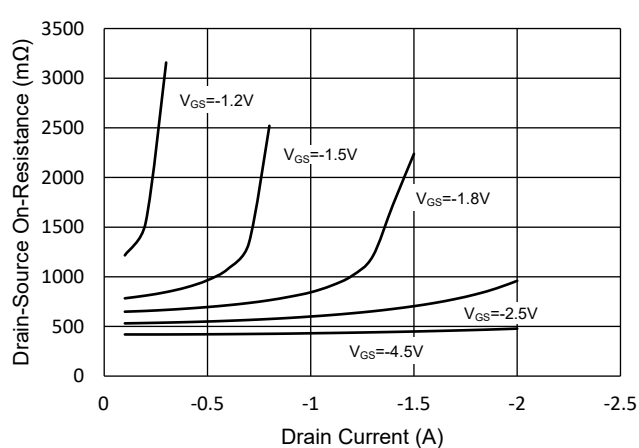


Fig.5 - Capacitance Characteristics

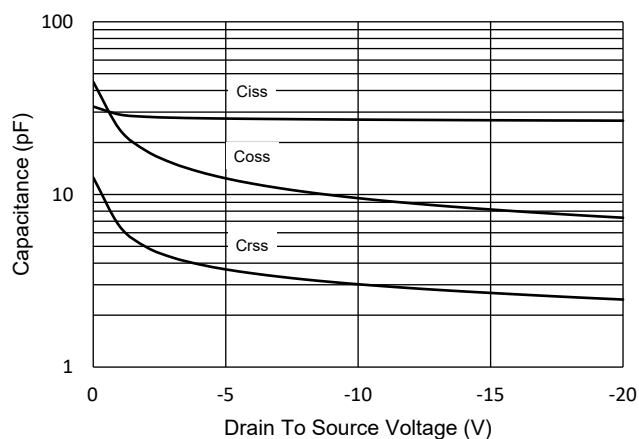
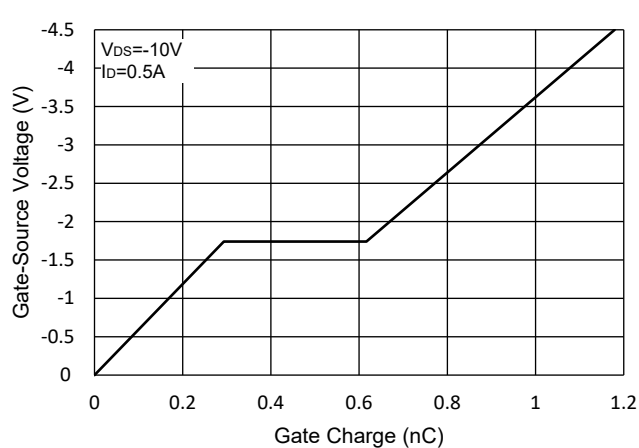


Fig.6 - Gate Charge



Curve Characteristics

Fig.7 - Normalized Threshold Voltage

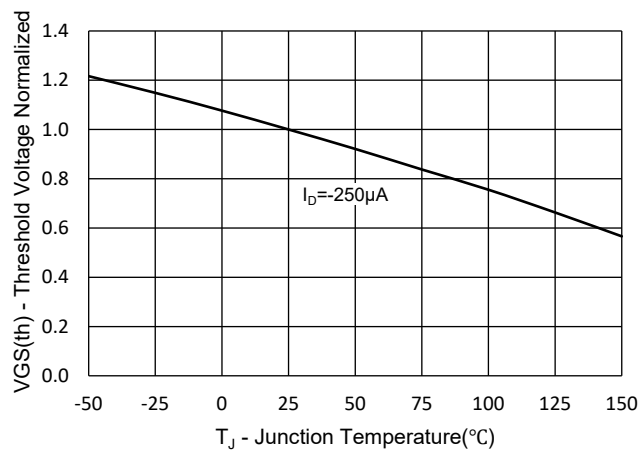


Fig.8 - Normalized On Resistance Characteristics

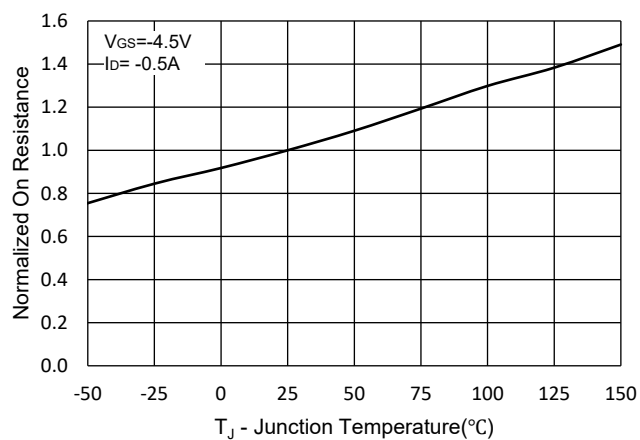


Fig.9 - I_S - V_{SD}

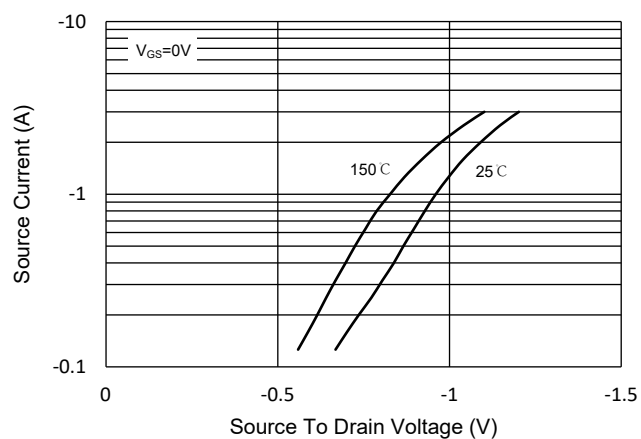


Fig.10 - Drain Current

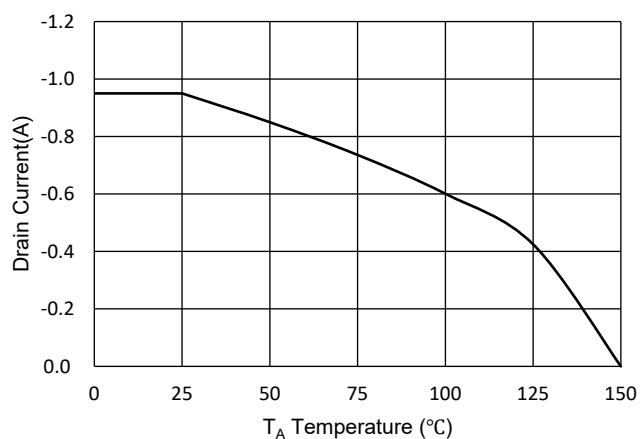
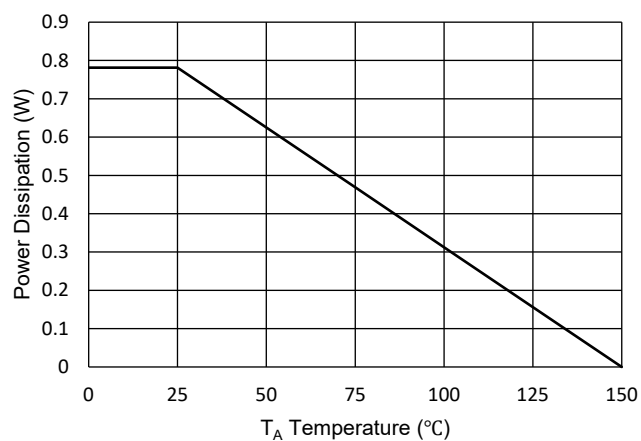


Fig.11 - PD Dissipation



Curve Characteristics

Fig.12 - Safe Operation Area

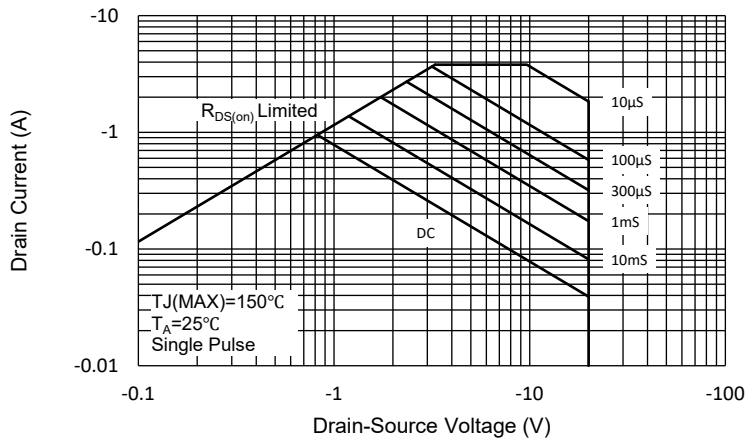
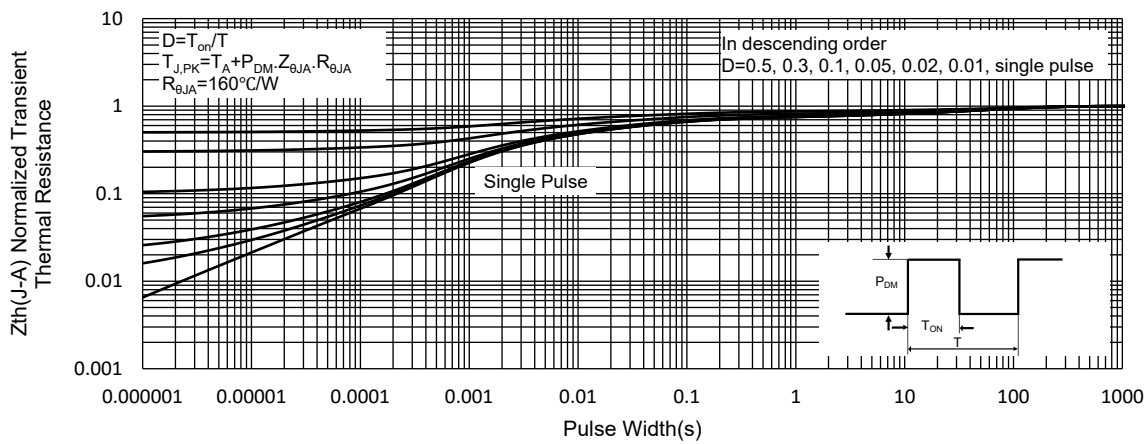


Fig.13 - Normalized Transient Thermal Impedance



Ordering Information

Device	Packing
Part Number-TP	Tape&Reel:10Kpcs/Reel

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